



## Description

The TD101X series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar phototransistor detector in a plastic LSO package with the robust coplanar double mold structure.

TD101X series provide the most stable isolation feature.

## Features

High isolation (000) \* +S

Temperature flexibility available see order information

DC input with transistor output

Operating temperature range: (-40 to 110 °C)

Output current: 100 mA, RoHS compliance

UL class 1

Regulatory Approvals

2L, 2L1 (33)

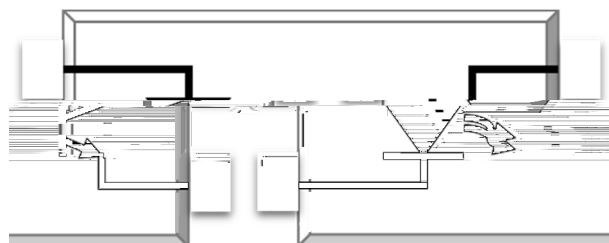
1D1, 1450313, (6) D10771, (8)

9, : G; !< != #1% G; 77<7

## Applications

- Switch mode power supplies
- Programmable controllers
- Household appliances
- Office equipment

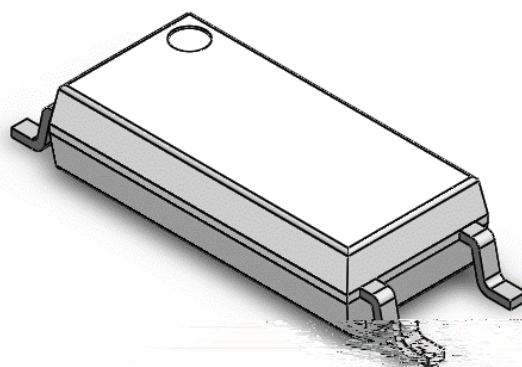
## SCHEMATIC



## PIN DEFINITION

1. Anode
2. Cathode
3. Emitter
4. Collector

## PACKAGE OUTLINE





A ' SO# " TE MA (IM " M ) ATIN ! S				
A * A+ 1T1 *	S@+ ; OL	)AL21	24AT	4OT1
A4 2T				
Borward , urrent	A <sub>B</sub>	50	mA	
ea" Borward , urrent	A <sub>B</sub>	1	A	1
* e&erse )oltage	) *	5	)	
Anput ower Dissipation	A	100	m\$	
O2T 2T				
, ollector . 1mitter )oltage	) , 10	70	)	
1mitter . , ollector )oltage	) 1 , 0	3	)	
, ollector , urrent	A ,	(0	mA	
Output ower Dissipation	o	1(0	m\$	
, O+ +O4				
Total ower Dissipation	tot	?(0	m\$	
Asolation )oltage	) iso	(000	) rms	?
Operating Temperature	Topr	. ( (C110	/ ,	
Storage Temperature	Tstg	. ( (C1?(	/ ,	
Soldering Temperature	Tsol	?50	/ ,	

Note 1. 100µs pulse, 100 ! "#e\$uenc%

Note 2. A& 'o# 1 ( )nute, R. . \* +0 , -0.



ELECTRICAL CHARACTERISTICS at Ta=25°C								
Symbol	Unit	Min	Typ	Max	Test Condition	Notes	Ref	
Forward Voltage	V <sub>B</sub>	-	1.1	1.5	I <sub>F</sub> = 10 mA, I <sub>R</sub> = 0	V <sub>B</sub> (0 mA)		
Reverse Current	I <sub>R</sub>	-	-	10	V <sub>R</sub> = 5 V	I <sub>R</sub> (5 V)		
Input Capacitance	C <sub>in</sub>	-	0	?	f = 1 MHz	C <sub>D</sub> (1 MHz)		
Collector Dark Current	I <sub>C0</sub>	-	-	100	V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0	I <sub>C0</sub> (5 V)		
Collector Emitter Saturation Voltage	V <sub>CE(sat)</sub>	0.7	-	-	I <sub>C</sub> = 1 mA, I <sub>B</sub> = 1 mA	V <sub>CE(sat)</sub> (1 mA)		
Emitter Saturation Voltage	V <sub>BE(sat)</sub>	0.3	-	-	I <sub>C</sub> = 1 mA, I <sub>B</sub> = 1 mA	V <sub>BE(sat)</sub> (1 mA)		
TRANSFER CHARACTERISTICS								
Current Transfer Ratio	TD1010	I <sub>C</sub> = I <sub>B</sub>	0	-	500	G	I <sub>B</sub> (mA), I <sub>C</sub> (mA)	
	TD101(		0	-	100			
	TD1015		100	-	0			
	TD1013		70	-	150			
	TD1017		10	-	250			
	TD101<		200	-	100		I <sub>B</sub> (10 mA), I <sub>C</sub> (mA)	
	TD1011		50	-	0			
	TD101?		5	-	10			
	TD101=		100	-	200			
	TD101!		150	-	20			
	TD101?		??	-	-			I <sub>B</sub> (1 mA), I <sub>C</sub> (mA)
	TD101=		=!	-	-			
TD101!	(5	-	-					
Collector Emitter Saturation Voltage	V <sub>CE(sat)</sub>	-	0.1	0.5	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1 mA	V <sub>CE(sat)</sub> (10 mA)		
Isolation Resistance	R <sub>ISO</sub>	10 <sup>11</sup>	10 <sup>11</sup>	-	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 50 μA	R <sub>ISO</sub> (5 V)		
Bloating Capacitance	C <sub>BO</sub>	-	0	1	f = 1 MHz	C <sub>D</sub> (1 MHz)		
Turn-off Frequency	f <sub>ce</sub>	-	70	-	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA, I <sub>B</sub> = 1 mA	f <sub>ce</sub> (1 mA)	=	
Response Time (t <sub>rise</sub> )	t <sub>r</sub>	-	(	17	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	t <sub>r</sub> (1 mA)	!	
Response Time (t <sub>fall</sub> )	t <sub>f</sub>	-	5	17	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	t <sub>f</sub> (1 mA)	!	

Note 1. I<sub>C</sub> = 10 mA

Note 2. I<sub>B</sub> = 1 mA



**CHARACTERISTICS) - ES**

<b>Fi..1 For /ard C&amp;rrent 0\$. Am1ient Tem%erat&amp;re</b>	<b>Fi..2 Collector Po /er Di\$\$i%ation 0\$. Am1ient Tem%erat&amp;re</b>
<b>Fi..3 For /ard C&amp;rrent 0\$. For /ard -olta .e</b>	<b>Fi..4 Collector Dar2 C&amp;rrent 0\$. Am1ient Tem%erat&amp;re</b>

**Fi..+ Collector C&rrent  
0\$. Collector3emitter -olta .e**

**Fi..4 Collector C&rrent**



CHARACTERISTIC CURVES

Fig. 5 Normalized Current Transfer Ratio vs. Collector Current

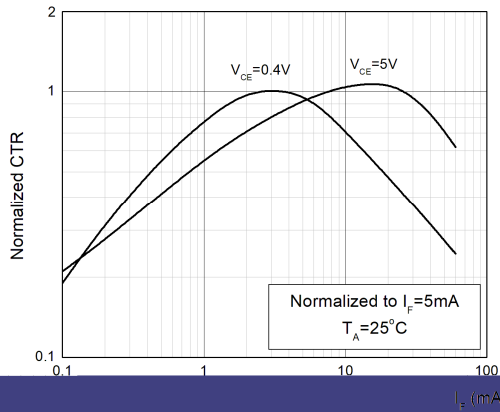


Fig. 8 Normalized Current Transfer Ratio vs. Ambient Temperature

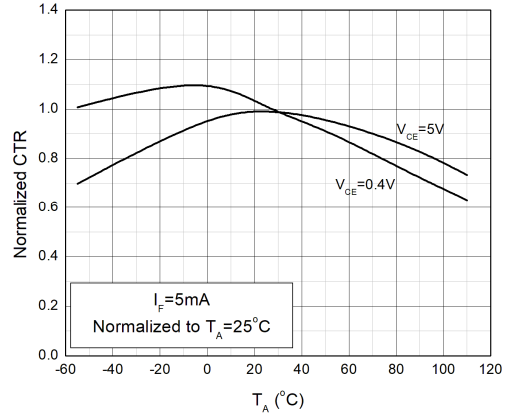


Fig. 9 Collector-Emitter Saturation Voltage vs. Ambient Temperature

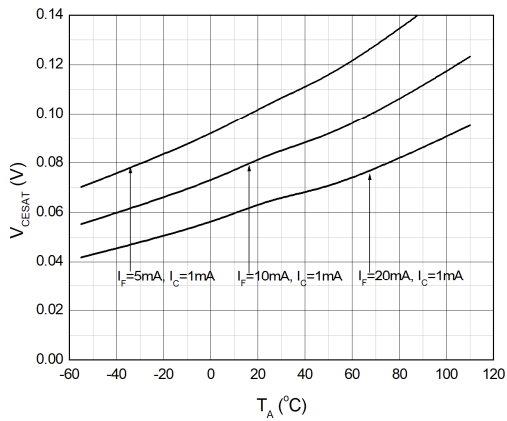


Fig. 10 Switching Time vs. Load Resistance

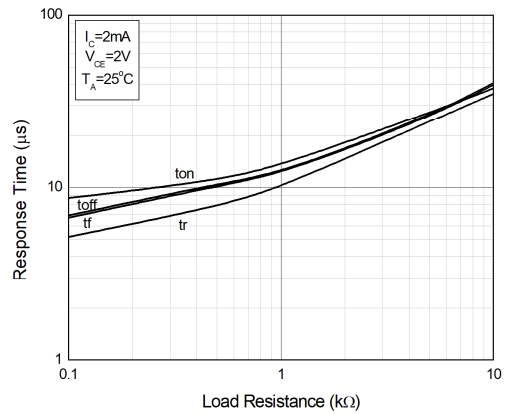
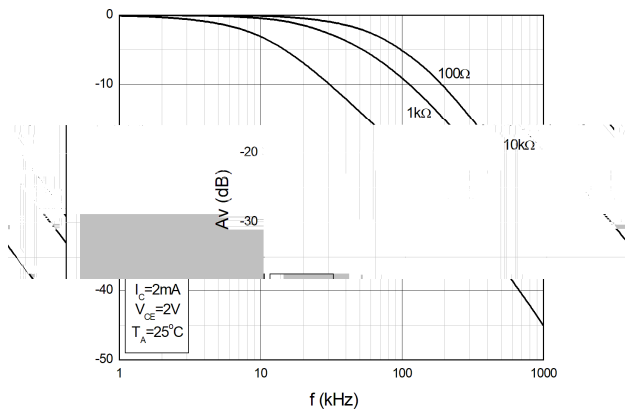


Fig. 11 Frequency Response



### TEST CIRCUITS

Fig. 12 Test Circuit of Forward Time

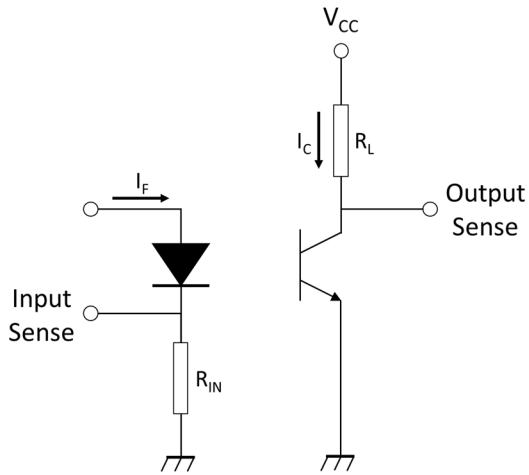


Fig. 13 Characteristic of Forward Time

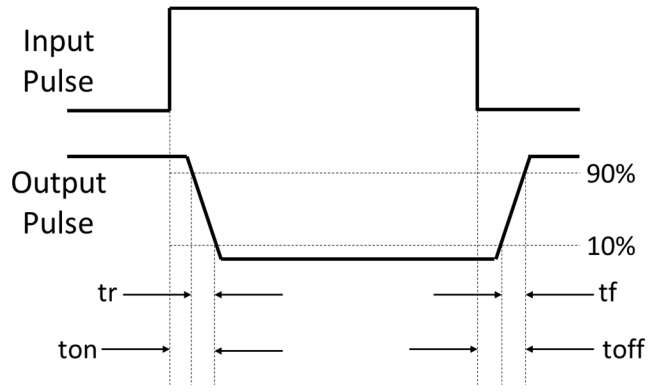
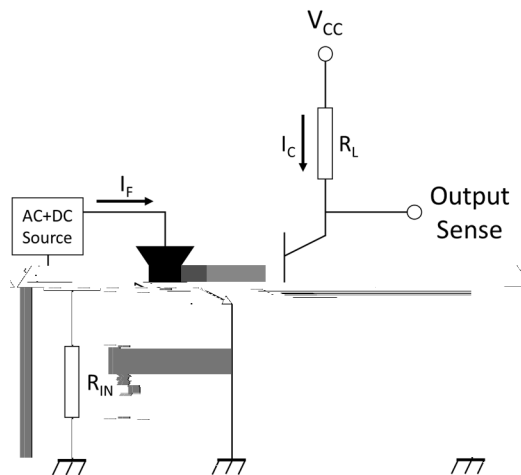
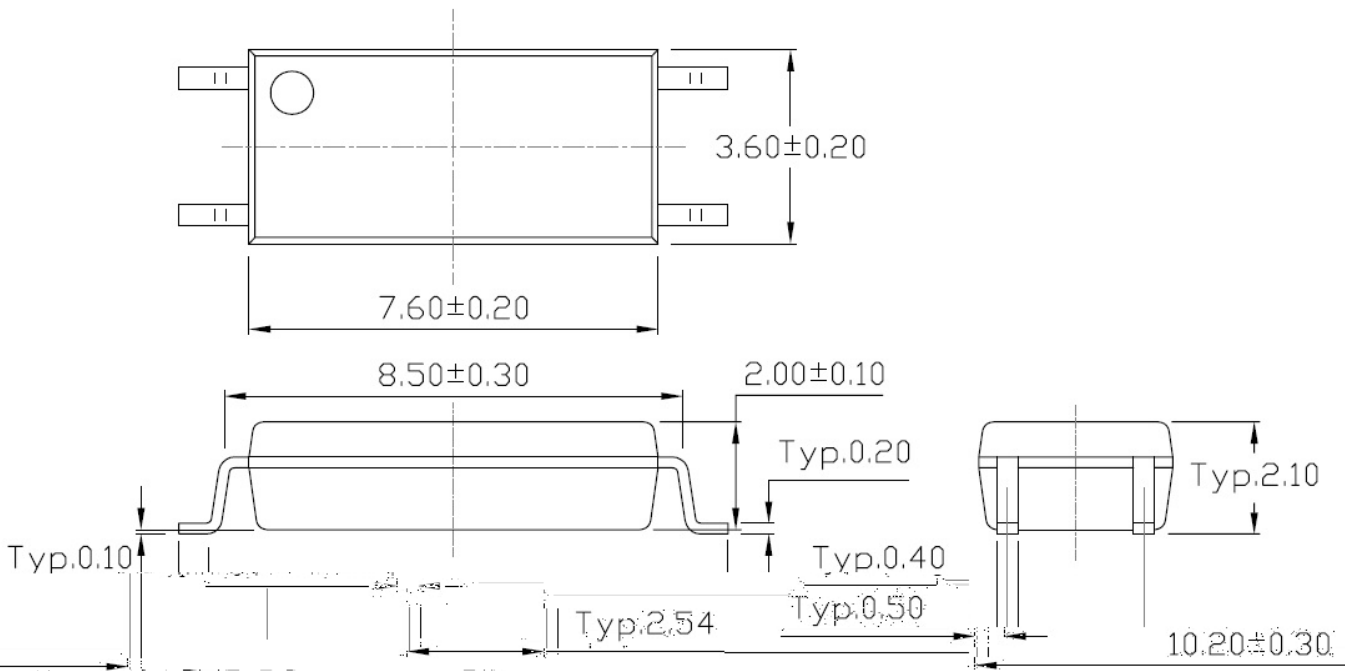


Fig. 14 Test Circuit of Reverse Time

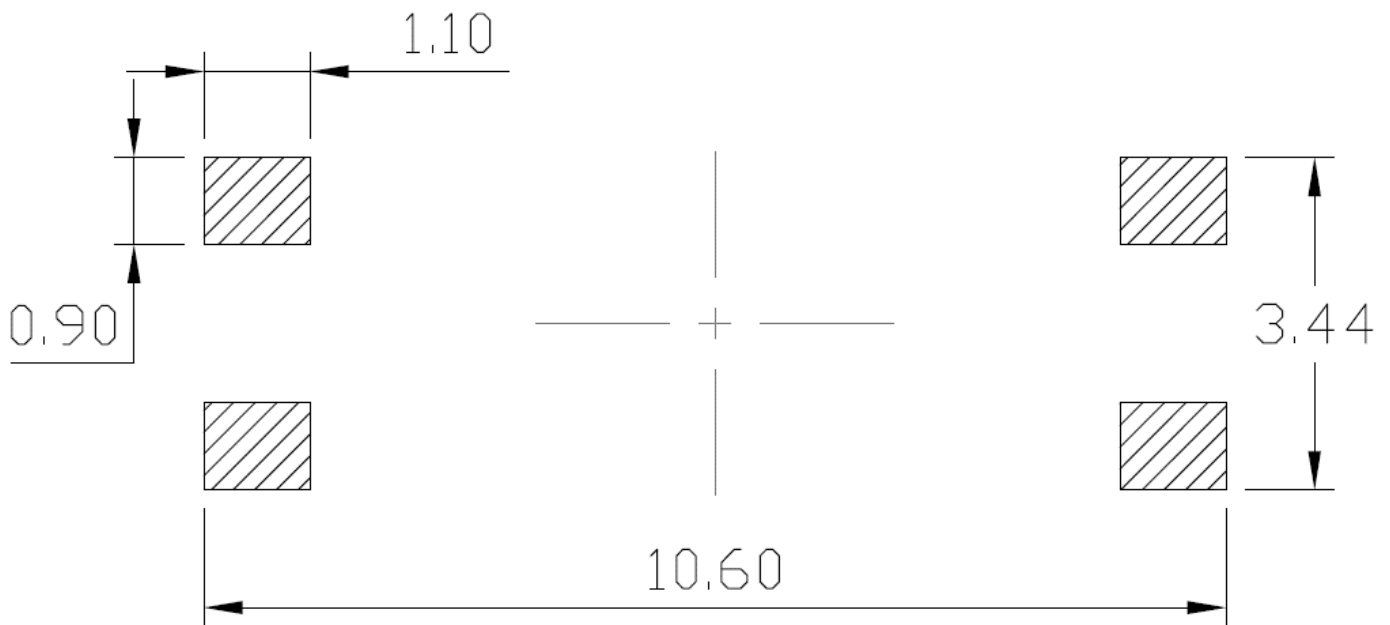




**PAC A ! E DIMENSIONS** Dimension\$ in mm & nle\$\$ other / i\$e \$tated=



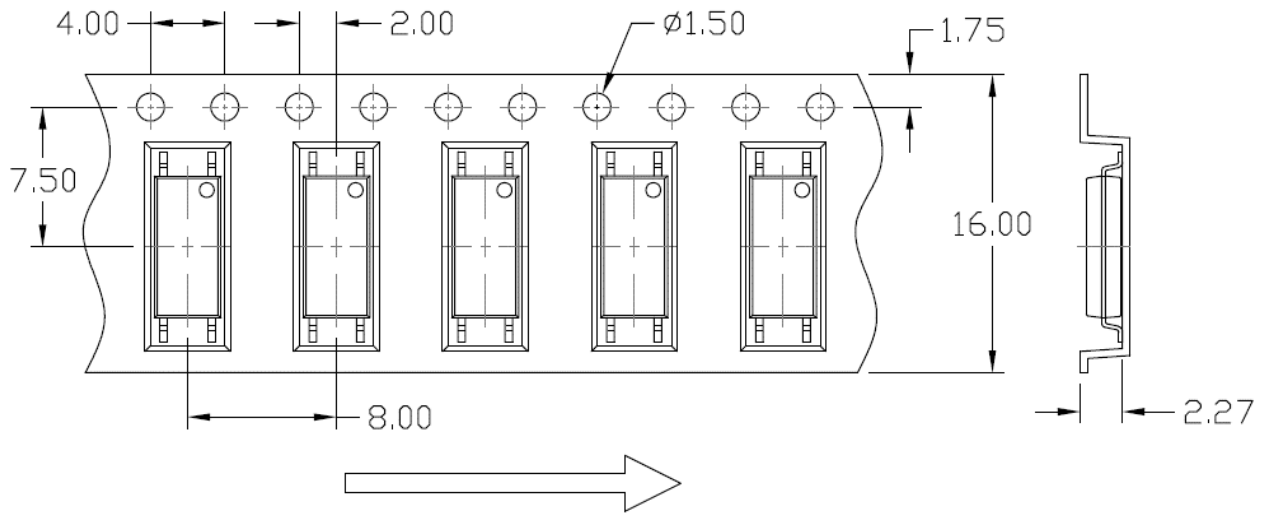
**RECOMMENDED SIDE MOUNTING DIMENSIONS** Dimension\$ in mm & nle\$\$ other / i\$e \$tated=



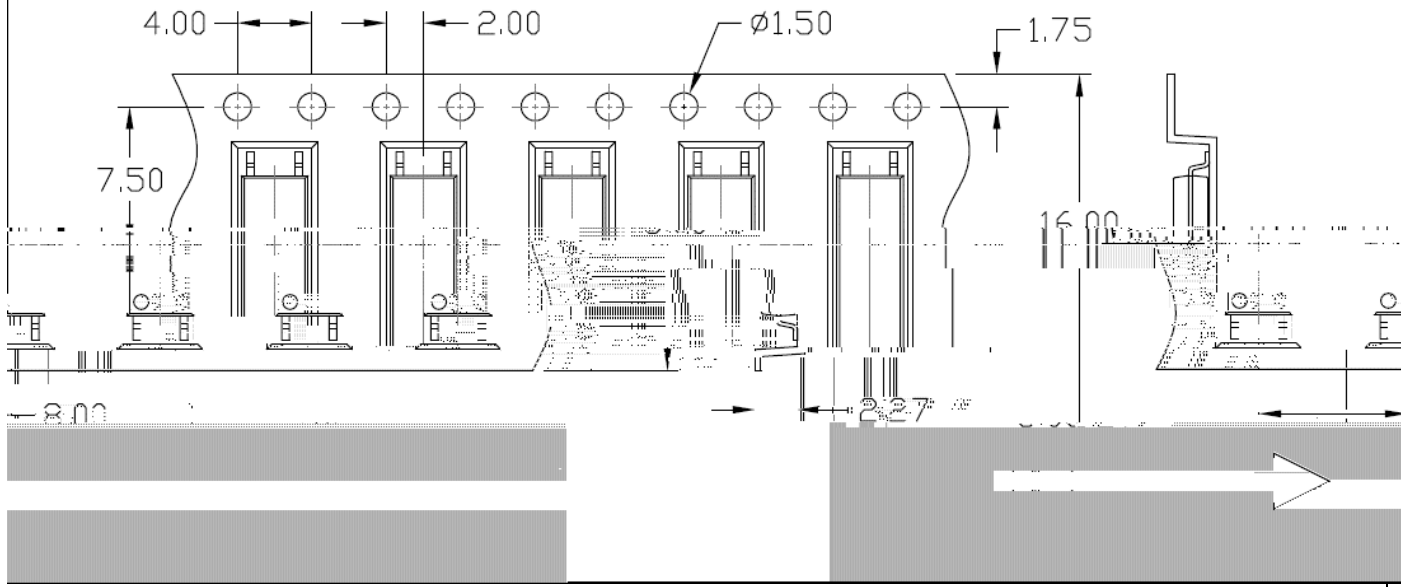


CA) ) IE) TAPE SPECIFICATIONS Dimension\$ in mm &nle\$\$ other / i\$e \$tated=

O%tion T1



O%tion T2

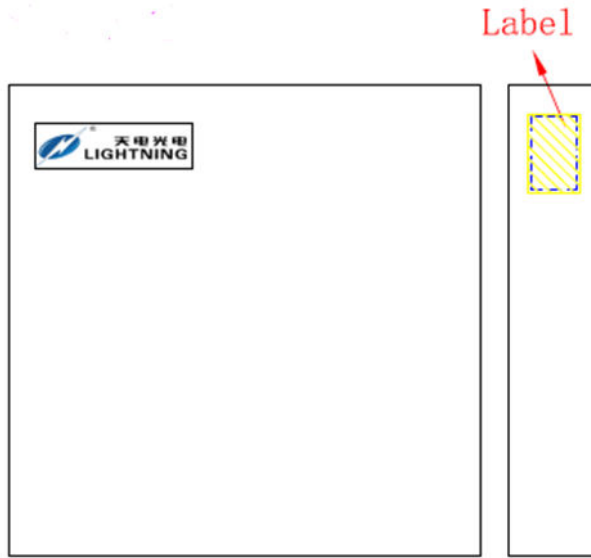






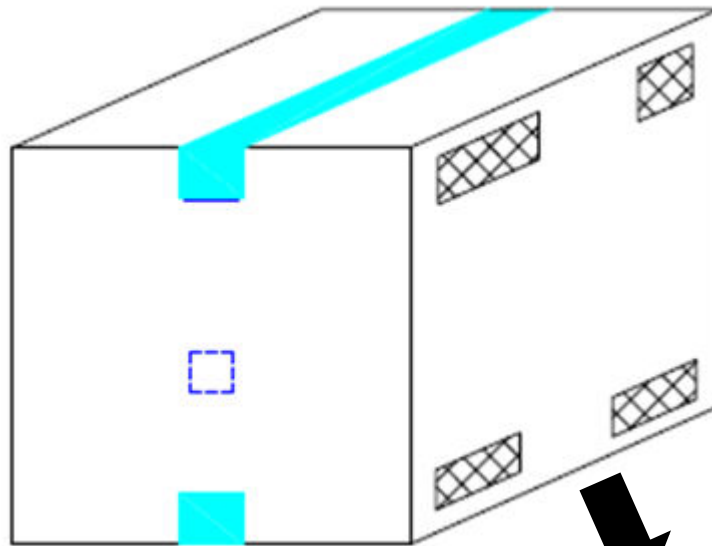
' O ( SPECIFICATIONS ) eel T<%e=

Inner ' o?

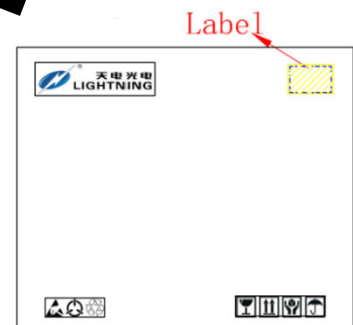


23 W 3 \* /-cm 3 /-cm 3 -.9cm

O&ter ' o?



23 W 3 \* +5cm 3 /4cm 3 /4cm





**O)DE)IN! AND MA) IN! INFO)MATION**

**MA) IN! INFO)MATION**




**TD**      @ Com%an< A11r.  
**1:1(**    @ Part N&m1er > )an2  
**-**        @ -DE O%tion  
**A**        @ Fi\$cal Aear  
**A**        @ Man&7act&rin. Code  
**B B**     @ Bor2 Bee2

**O)DE)IN! INFO)MATION**

**#A'E# INFO)MATION**

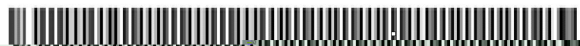
**TD1:1 (CD=3! -**

**TD** : , ompany Abbr#  
**101X** : \*an" 60J1J?J=J!J(J5J3J7J<8  
**K** : Tape and \*eel Option 6T1JT?8  
**G** : Green  
**)** : )D1 Option 6) or 4one8



**福建天电光电有限公司**  
FUJIAN LIGHTNING OPTOELECTRONIC CO., LTD.




Part No : XXXXXXXXXXXXX      Bin Code : X



Lot No : XXXXXXXXXXXX

Date Code : XXXX

Q'ty : XXXX pcs

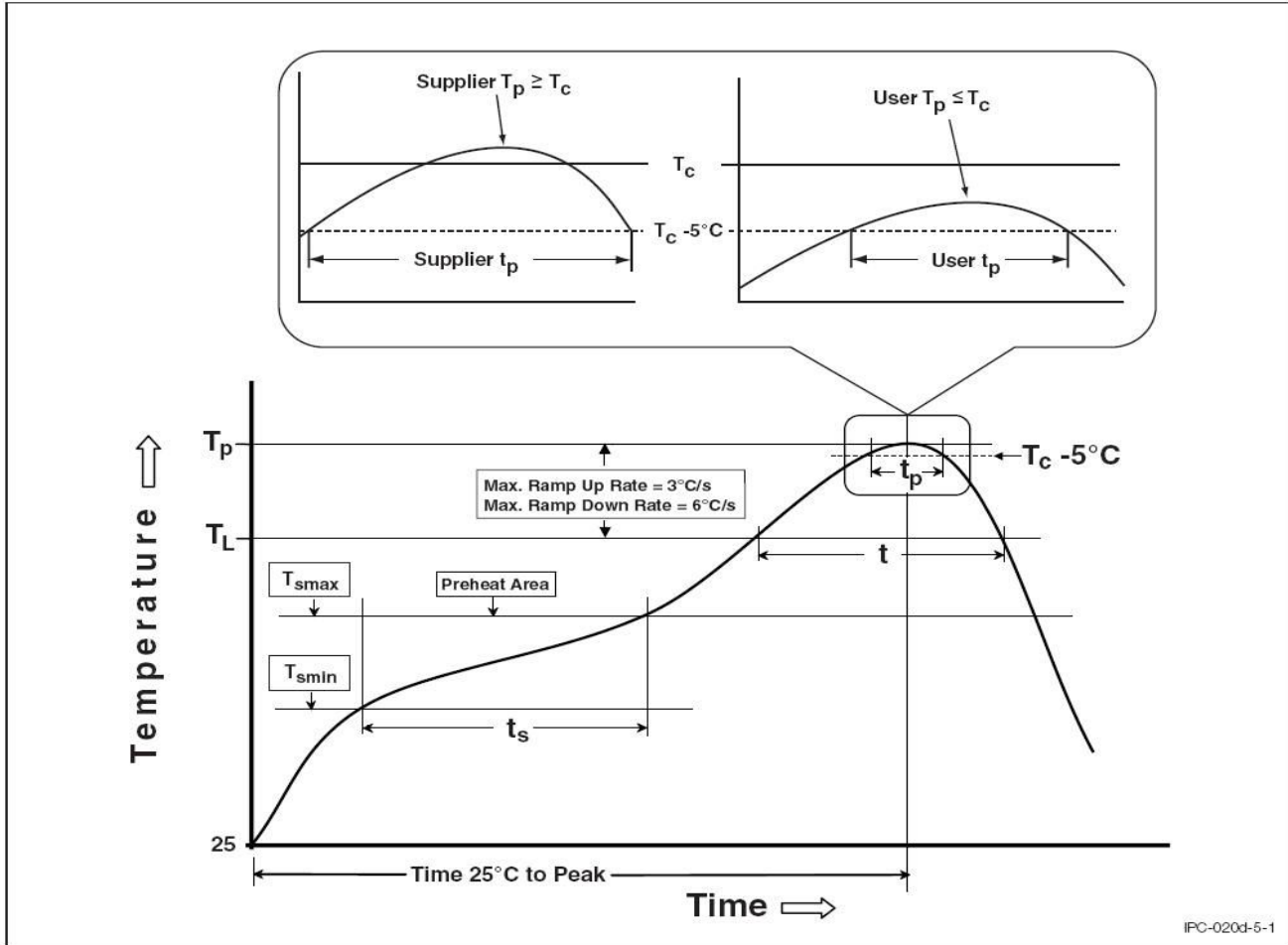
**PAC IN! E" ANTITA**

O%tion	E&antit<	E&antit< F Inner 1o?	E&antit< F O&ter 1o?
T1	=000 2nitsJ *eel	= *eelsJanner bo-	( Anner bo-JOuter bo- D ! (" 2nits
T?	=000 2nitsJ *eel	= *eelsJanner bo-	( Anner bo-JOuter bo- D ! (" 2nits



PROFILE INFORMATION

PROFILE



Profile Feature	Sn3P1 Assembly Profile	P13Free Assembly Profile
Temperature +in# $T_{smin}$	100	100
Temperature +a-# $T_{smax}$	100	100
Time $t_s$ from $T_{smin}$ to $T_{smax}$	50.1±0 seconds	50.1±0 seconds
* amp.up * ate $T_L$ to $T_p$	=/ , Jsecond ma-#	=/ , Jsecond ma-#
Liquidous Temperature $T_L$	175	175
Time $t_L$ + aintained Abo&e $T_L$	50 : 10 seconds	50 : 10 seconds
ea" ;ody ac"age Temperature	200	200
Time $t_p$ within ( / , of 200	±0 seconds	±0 seconds
* amp.down * ate $T_p$ to $T_L$	5/ , Jsecond ma-	5/ , Jsecond ma-
Time ( / , to ea" Temperature	5 minutes ma-#	7 minutes ma-#



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